Product data sheet

1. General description

P-channel enhancement mode Field-Effect Transistor (FET) in a 4 bumps Wafer Level Chip-Size Package (WLCSP) using Trench MOSFET technology.

2. Features and benefits

- Low threshold voltage
- Ultra small package: 0.78 × 0.78 × 0.35 mm
- Trench MOSFET technology
- ElectroStatic Discharge (ESD) protection > 2 kV HBM

3. Applications

- · Battery switch
- · High-speed line driver
- Low-side loadswitch
- Switching circuits

4. Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
V _{DS}	drain-source voltage	T _j = 25 °C		-	-	-12	V
V_{GS}	gate-source voltage			-8	-	8	V
I _D	drain current	$V_{GS} = -4.5 \text{ V}; T_{amb} = 25 \text{ °C}; t \le 5 \text{ s}$	[1]	-	-	-4.9	Α
Static characteristics							
R _{DSon}	drain-source on-state resistance	V_{GS} = -4.5 V; I_D = -3 A; T_j = 25 °C		-	55	65	mΩ

^[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated, mounting pad for drain 6 cm².





5. Pinning information

Table 2. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
A1	G	gate	1 2	D I
A2	S	source	A () ()	
B1	D	drain		$G \left(\begin{array}{c} \Psi \\ \overline{\Psi} \end{array} \right)$
B2	S	source	В	Y FIGURE 1
			Transparent top view WLCSP4 (OL- PMCM4401VPE)	S 017aaa259

6. Ordering information

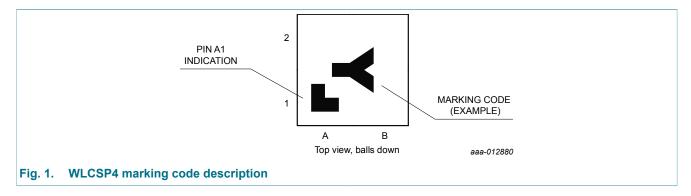
Table 3. Ordering information

Type number	Package	kage					
	Name	Description	Version				
PMCM4401VPE	WLCSP4	WLCSP4: wafer level chip-size package; 4 bumps (2 x 2)	OL-PMCM4401VPE				

7. Marking

Table 4. Marking codes

Type number	Marking code
PMCM4401VPE	Q



8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit	
V_{DS}	drain-source voltage	T _j = 25 °C		-	-12	V	
V_{GS}	gate-source voltage			-8	8	V	
I _D	drain current	$V_{GS} = -4.5 \text{ V}; T_{amb} = 25 ^{\circ}\text{C}; t \le 5 \text{ s}$	[1]	-	-4.9	Α	
		V _{GS} = -4.5 V; T _{amb} = 25 °C	[1]	-	-3.9	Α	
		V _{GS} = -4.5 V; T _{amb} = 100 °C	[1]	-	-2.5	Α	
I _{DM}	peak drain current	T_{amb} = 25 °C; single pulse; $t_p \le 10 \mu s$		-	-16	Α	
P _{tot}	total power dissipation	T _{amb} = 25 °C	[2]	-	400	mW	
			[1]	-	1300	mW	
		$T_{sp} = 25 ^{\circ}C$		-	12500	mW	
Tj	junction temperature			-55	150	°C	
T _{amb}	ambient temperature			-55	150	°C	
T _{stg}	storage temperature			-65	150	°C	
Source-drain diode							
I _S	source current	T _{amb} = 25 °C	[1]	-	-1.2	Α	

^[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated, mounting pad for drain 6 cm².

^[2] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.

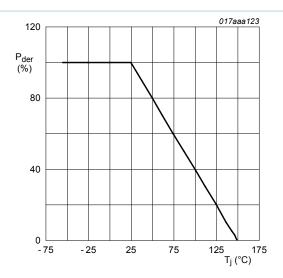


Fig. 2. MOSFET transistor: Normalized total power dissipation as a function of junction temperature

$$P_{der} = \frac{P_{tot}}{P_{tot(25^{\circ}C)}} \times 100 \%$$

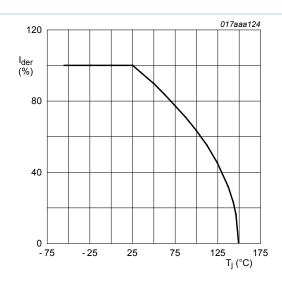


Fig. 3. MOSFET transistor: Normalized continuous drain current as a function of junction temperature

$$I_{der} = \frac{I_D}{I_{D(25^{\circ}C)}} \times 100 \%$$

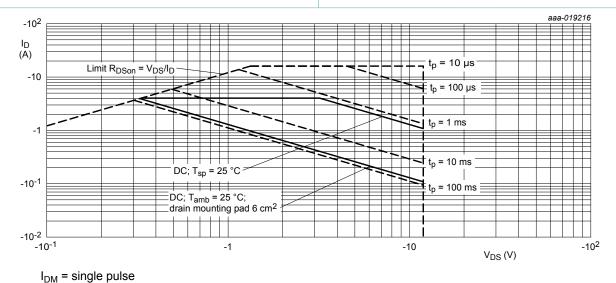


Fig. 4. Safe operating area; junction to ambient; continuous and peak drain currents as a function of drainsource voltage

9. Thermal characteristics

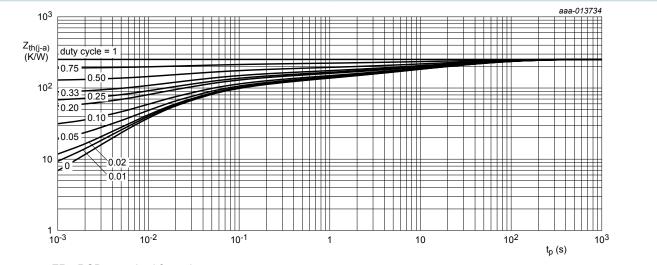
Table 6. Thermal characteristics

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
R _{th(j-a)}	thermal resistance	in free air	[1]	-	250	300	K/W
from junction to ambient	ļ		<u>[2]</u>	-	70	85	K/W
		<u>[3]</u>	-	85	100	K/W	

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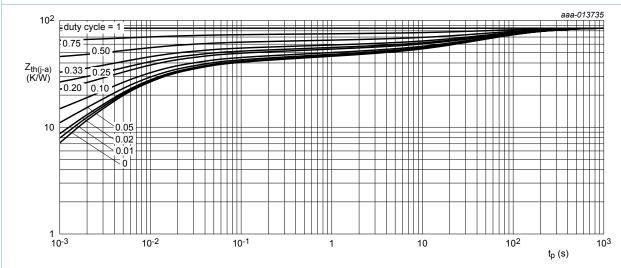
Symbol	Parameter	Conditions		Min	Тур	Max	Unit
		in free air; t ≤ 5 s	[3]	-	50	60	K/W
R _{th(j-sp)}	thermal resistance from junction to solder point			-	5	10	K/W

- [1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.
- [2] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for drain, 4-layer, 1 cm².
- [3] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for drain 6 cm².



FR4 PCB, standard footprint

Fig. 5. Transient thermal impedance from junction to ambient as a function of pulse duration; typical values



FR4 PCB, mounting pad for drain 6 cm²

Fig. 6. Transient thermal impedance from junction to ambient as a function of pulse duration; typical values

10. Characteristics

Table 7. Characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static chara	acteristics					
$V_{(BR)DSS}$	drain-source breakdown voltage	$I_D = -250 \mu A; V_{GS} = 0 V; T_j = 25 °C$	-12	-	-	V
V_{GSth}	gate-source threshold voltage	$I_D = -250 \mu A; V_{DS} = V_{GS}; T_j = 25 \text{ °C}$	-0.4	-0.6	-0.9	V
I _{DSS}	drain leakage current	V _{DS} = -12 V; V _{GS} = 0 V; T _j = 25 °C	-	-	-1	μΑ
I _{GSS}	gate leakage current	$V_{GS} = -8 \text{ V}; V_{DS} = 0 \text{ V}; T_j = 25 ^{\circ}\text{C}$	-	-	-10	μA
		V _{GS} = 8 V; V _{DS} = 0 V; T _j = 25 °C	-	-	10	μΑ
		$V_{GS} = -4.5 \text{ V}; V_{DS} = 0 \text{ V}; T_j = 25 ^{\circ}\text{C}$	-	-	-1	μA
		V _{GS} = 4.5 V; V _{DS} = 0 V; T _j = 25 °C	-	-	1	μΑ
		V_{GS} = -2.5 V; V_{DS} = 0 V; T_j = 25 °C	-	-	-200	nA
		V _{GS} = 2.5 V; V _{DS} = 0 V; T _j = 25 °C	-	-	200	nA
200	drain-source on-state	V_{GS} = -4.5 V; I_D = -3 A; T_j = 25 °C	-	55	65	mΩ
	resistance	V_{GS} = -4.5 V; I_D = -3 A; T_j = 150 °C	-	73	86	mΩ
		V_{GS} = -2.5 V; I_D = -2 A; T_j = 25 °C	-	77	96	mΩ
		V_{GS} = -1.8 V; I_D = -0.1 A; T_j = 25 °C	-	110	160	mΩ
9 _{fs}	forward transconductance	$V_{DS} = -6 \text{ V}; I_D = -3 \text{ A}; T_j = 25 ^{\circ}\text{C}$	-	13.6	-	S
R _G	gate resistance	f = 1 MHz	-	5.5	-	Ω
Dynamic ch	naracteristics		1			
Q _{G(tot)}	total gate charge	$V_{DS} = -6 \text{ V}; I_D = -3 \text{ A}; V_{GS} = -4.5 \text{ V};$	-	6.8	10	nC
Q_{GS}	gate-source charge	T _j = 25 °C	-	0.8	-	nC
Q_{GD}	gate-drain charge		-	2.2	-	nC
C _{iss}	input capacitance	V _{DS} = -6 V; f = 1 MHz; V _{GS} = 0 V;	-	415	-	pF
C _{oss}	output capacitance	T _j = 25 °C	-	195	-	pF
C _{rss}	reverse transfer capacitance		-	165	-	pF
t _{d(on)}	turn-on delay time	$V_{DS} = -6 \text{ V}; I_D = -3.5 \text{ A}; V_{GS} = -4.5 \text{ V};$	-	4.8	-	ns
t _r	rise time	$R_{G(ext)} = 6 \Omega$; $T_j = 25 ^{\circ}C$	-	24.7	-	ns
t _{d(off)}	turn-off delay time		-	25.1	-	ns
t _f	fall time		-	16.5	-	ns
Source-dra	in diode		'	,		
V _{SD}	source-drain voltage	$I_S = -1.2 \text{ A}; V_{GS} = 0 \text{ V}; T_j = 25 ^{\circ}\text{C}$	-	-0.8	-1.2	V

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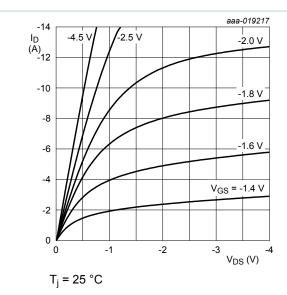
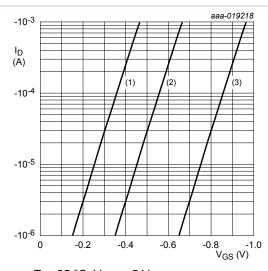


Fig. 7. Output characteristics: drain current as a function of drain-source voltage; typical values



$$T_j = 25 \, ^{\circ}C; \, V_{DS} = -5 \, V$$

- (1) minimum values
- (2) typical values
- (3) maximum values

Fig. 8. Sub-threshold drain current as a function of gate-source voltage

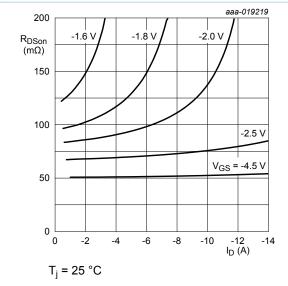


Fig. 9. Drain-source on-state resistance as a function of drain current; typical values

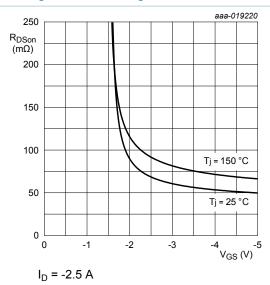


Fig. 10. Drain-source on-state resistance as a function of gate-source voltage; typical values

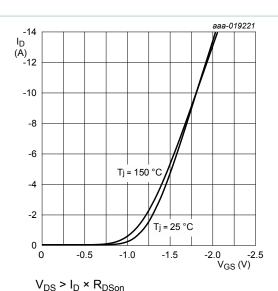


Fig. 11. Transfer characteristics: drain current as a function of gate-source voltage; typical values

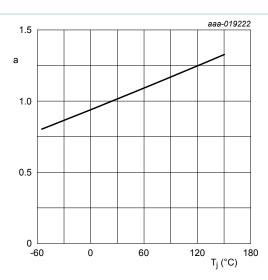
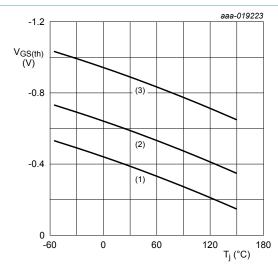


Fig. 12. Normalized drain-source on-state resistance as a function of junction temperature; typical values

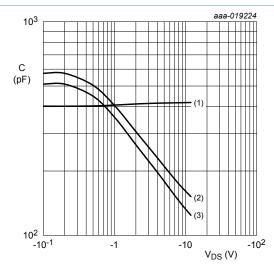
$$a = \frac{R_{DSon}}{R_{DSon(25^{\circ}C)}}$$



 $I_D = -0.25 \text{ mA}; V_{DS} = V_{GS}$

- (1) minimum values
- (2) typical values
- (3) maximum values

Fig. 13. Gate-source threshold voltage as a function of junction temperature



 $f = 1 MHz; V_{GS} = 0 V$

- (1) C_{iss}
- (2) C_{oss}
- (3) C_{rss}

Fig. 14. Input, output and reverse transfer capacitances as a function of drain-source voltage; typical values

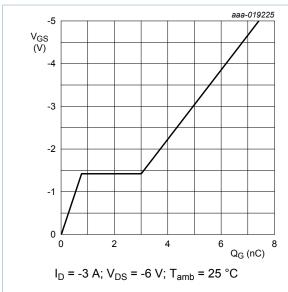


Fig. 15. Gate-source voltage as a function of gate charge; typical values

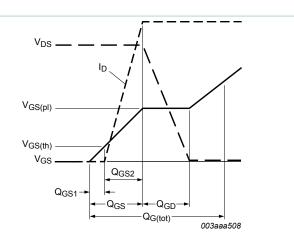


Fig. 16. MOSFET transistor: Gate charge waveform definitions

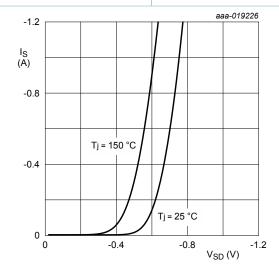
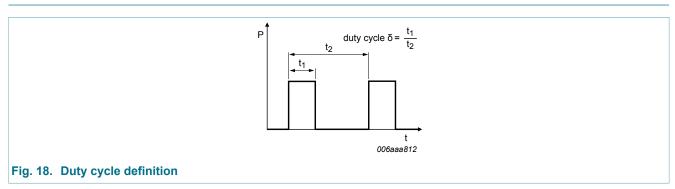


Fig. 17. Source current as a function of source-drain voltage; typical values

11. Test information

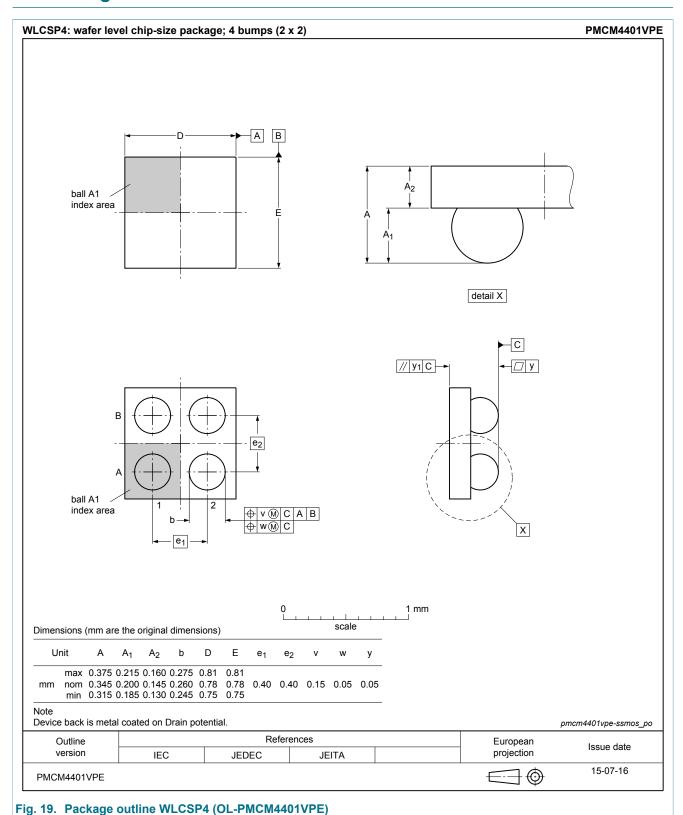
 $V_{GS} = 0 V$



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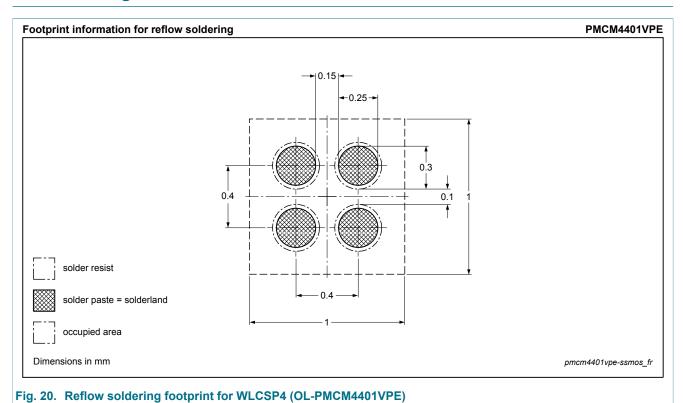
12. Package outline



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13. Soldering



14. Revision history

Table 8. Revision history

Data sheet ID	Release date	Data sheet status	Change notice	Supersedes
PMCM4401VPE v.1	20150729	Product data sheet	-	-

15. Legal information

15.1 Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
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16. Contents

1	General description	1
2	Features and benefits	1
3	Applications	1
4	Quick reference data	1
5	Pinning information	2
6	Ordering information	2
7	Marking	2
8	Limiting values	3
9	Thermal characteristics	4
10	Characteristics	6
11	Test information	9
12	Package outline	10
13	Soldering	11
14	Revision history	12
15	Legal information	13
15.1	Data sheet status	13
15.2	Definitions	13
15.3	Disclaimers	13
15.4	Trademarks	14

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